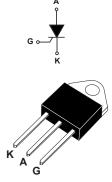


BTW69-1200

Datasheet

50 A 1200 V SCR in TOP3 insulated



TOP3 Isolated

Features

- Max. repetitive blocking voltage = V_{DRM}, V_{RRM} = 1200 V
- I_{GT} maximum = 80 mA
- ECOPACK2 component (RoHS and HF compliance)
- Complies with UL 1557 standard (File ref : E81734)

Applications

- Solid state relays
- Welding equipment
- High power motor control
- Heating systems
- Controlled AC/DC bridge

Description

Available in a high power package TOP3-I, the BTW69-1200 is suitable in applications where power handling and power dissipation are critical, such as solid state relays, welding equipment, high power motor control and power converters.

This device offers a superior performance in surge current handling capabilities, allowing usage in industrial environment.

Thanks to its internal ceramic pad, it provide high voltage insulation ($2500V_{RMS}$), complying with UL standards (file ref: E81734).

Product status link		
BTW69-1200		
Product summary		
I _{T(RMS)}	50 A	
V _{DRM} /V _{RRM}	1200 V	
I _{GT}	80 mA	

1 Characteristics

Symbol	Parameters				Unit	
I _{T(RMS)}	RMS on-state current (180° conduction angle) $T_c = 75 \text{ °C}$				Α	
IT _(AV)	Average on-state current $T_c = 75 \ ^{\circ}C$ (180° conduction angle)			32	A	
1	$t_p = 8.3 \text{ ms}$			610	•	
ITSM	I_{TSM} Non repetitive surge peak on-state current (full cycle, T_j initial = 25 °C, V_R = 0 V) t_p = 10 ms		580	A		
l ² t	I ² t value for fusing	t _p = 10 ms, T _j = 25°C		1680	A ² s	
dl/dt	Critical rate of rise of on-state current $I_G = 2 \times I_{GT}$, $t_r \le 100 \text{ ns}$	F = 60 Hz	T _j = 125 °C	50	A/µs	
I _{GM}	Peak gate current $t_p = 20 \ \mu s$ $T_j = 125 \ ^{\circ}C$		8	Α		
P _{G(AV)}	Average gate power dissipation $T_j = 125 \text{ °C}$				W	
T _{stg}	Storage junction temperature range			-40 to +150	°C	
Тj	Operating junction temperature range			-40 to +125	°C	
V _{GRM}	Maximum peak reverse gate voltage			5	V	
V _{ins}	Insulation RMS voltage, 1 minute			2500	V	

Table 1. Absolute maximum ratings

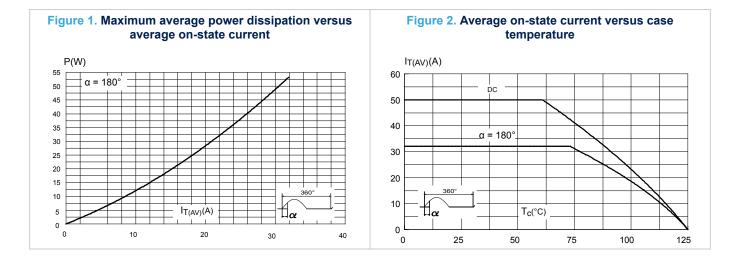
Table 2. Electrical characteristics (T_j = 25°C, unless otherwise specified)

Symbol	Test conditions		Value	Unit	
			Min.	8	– mA
I _{GT}	V_D = 12 V, R_L = 33 Ω	-	Max	80	- MA
V _{GT}				1.3	V
V _{GD}	$V_D = V_{DRM}, R_L = 3.3 \text{ k}\Omega$	125 °C	Min.	0.2	V
I _H	I _H I _T = 500 mA, gate open				mA
١L	$I_{G} = 1.2 \times I_{GT}$	Max.	200	mA	
dV/dt	V _D = 67 %, V _{DRM} gate open	125 °C	Min.	1000	V/µs
V _{TM}	I _{TM} = 100 A, t _p = 380 μs		Max.	1.9	V
V _{TO}	Threshold on-state voltage	125 °C	Max.	1.0	V
R _D	On-state dynamic resistance	125 °C	Max.	8.5	mΩ
		25 °C	Мах	10	μA
I _{DRM} /I _{RRM}	$V_D = V_{DRM}, V_R = V_{RRM}$	125 °C	Max.	5	mA

Table 3. Thermal resistance

Symbol	Parameters	Value	Unit
R _{th(j-c)}	Junction to case (D.C)	0.9	°C/W
R _{th(j-a)}	Junction to ambiant (D.C) 50		0/10

1.1 Characteristics (curves)



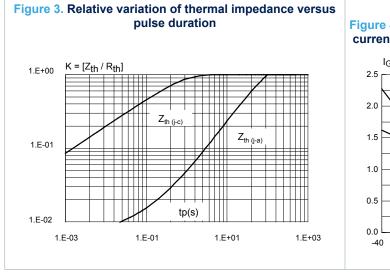
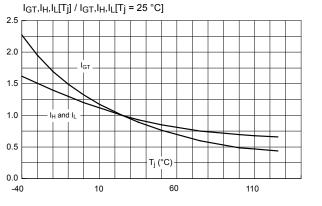


Figure 4. Relative variation of gate trigger current, holding current and latching current versus junction temperature





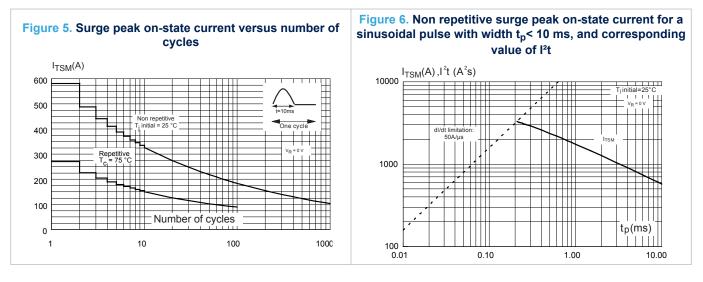
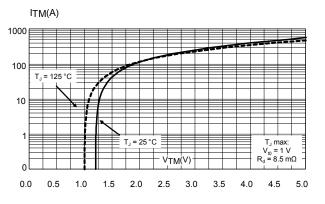


Figure 7. On-state characteristics (maximum values)



2 Package information

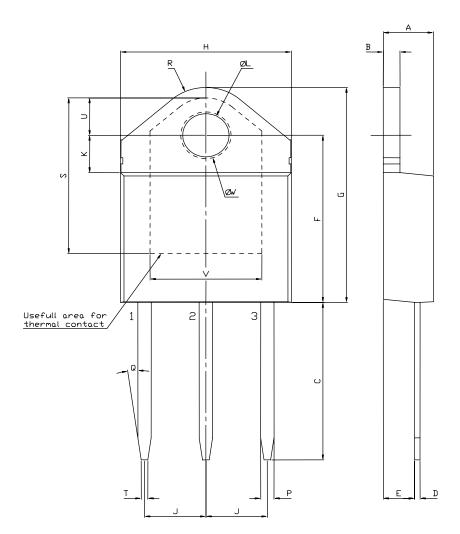
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In order to meet environmental requirements, ST offers these devices in different grades of ECOPACK packages, depending on their level of environmental compliance. ECOPACK specifications, grade definitions and product status are available at: www.st.com. ECOPACK is an ST trademark.

2.1 TOP3 Ins. package information

- ECOPACK® (Lead-free plating and Halogen free package compliance)
- Lead-free package leads finishing
- Halogen-free molding compound resin meets UL94 standard level V0
- Recommended torque: 1.05 N·m (max. torque: 1.2 N·m)

Figure 8. TOP3 Isolated package outline



			[Dimensions		
Ref.		mm			Inches ⁽¹⁾	
	Min.	Тур.	Max.	Min.	Тур.	Max.
А	4.40		4.60	0.1732		0.1811
В	1.45		1.55	0.0571		0.0610
С	14.35		15.60	0.5650		0.6142
D	0.50		0.70	0.0197		0.0276
E	2.70		2.90	0.1063		0.1142
F	15.80		16.50	0.6220		0.6496
G	20.40		21.10	0.8031		0.8307
Н	15.10		15.50	0.5945		0.6102
J	5.40		5.65	0.2126		0.2224
к	3.40		3.65	0.1339		0.1437
L	4.08		4.17	0.1606		0.1642
М	1.20		1.40	0.0472		0.0551
R		4.60			0.1811	

Table 4. TOP3 Isolated mechanical data

1. Inches given for reference only



3 Ordering information

Figure 9. Ordering information scheme

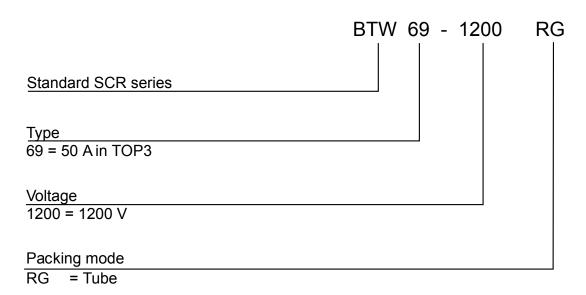


Table 5. Ordering information

Order code	Marking	Package	Weight	Base qty.	Delivery mode
BTW69-1200RG	BTW691200	TOP3 Ins.	4.5 g	30	Tube

Revision history

Table 6. Document revision history

Date	Revision	Changes
09-Sep-2019	1	Initial release.



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